

### Typical Applications

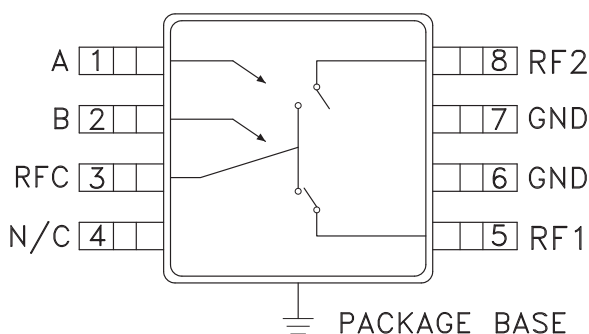
The HMC536MS8G / HMC536MS8GE is ideal for:

- Cellular/PCS/3G Infrastructure
- ISM/MMDS/WiMAX
- CATV/CMTS
- Test Instrumentation

### Features

- Input P0.1dB: +34 dBm @ +5V
- Insertion Loss: 0.5 dB
- Positive Control: +3V or +5V
- MS8G SMT Package, 14.8 mm<sup>2</sup>
- Isolation: 27 dB
- Very Fast Switching Speed
- Included in the HMC-DK005 Designer's Kit

### Functional Diagram



### General Description

The HMC536MS8G & HMC536MS8GE are DC to 6 GHz GaAs MMIC T/R switches in 8 lead MSOP8G surface mount packages with an exposed ground paddle. The switch is ideal for cellular/PCS/3G basestation applications featuring low 0.5 dB insertion loss and +55 dBm input IP3. Power handling is excellent up through 6 GHz with the switch offering a P0.1dB compression point of +29 dBm at +3 volts control. On-chip circuitry allows positive voltage control of 0/+3 volts or 0/+5 volts at very low DC currents.

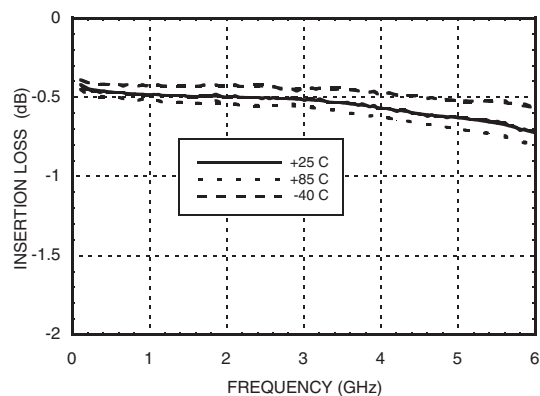
### Electrical Specifications, $T_A = +25^\circ \text{C}$ , $V_{ctl} = 0/+3 \text{ Vdc}$ to $+5 \text{ Vdc}$ , 50 Ohm System

| Parameter                                                                                                        | Frequency     | Min. | Typ. | Max. | Units |
|------------------------------------------------------------------------------------------------------------------|---------------|------|------|------|-------|
| Insertion Loss                                                                                                   | DC - 3.0 GHz  |      | 0.5  | 0.8  | dB    |
|                                                                                                                  | DC - 4.5 GHz  |      | 0.6  | 0.9  | dB    |
|                                                                                                                  | DC - 6.0 GHz  |      | 0.7  | 1.0  | dB    |
| Isolation (RFC to RF1/RF2)                                                                                       | DC - 4.0 GHz  | 23   | 27   |      | dB    |
|                                                                                                                  | 4.0 - 5.0 GHz | 26   | 30   |      | dB    |
|                                                                                                                  | 5.0 - 6.0 GHz | 27   | 32   |      | dB    |
| Return Loss                                                                                                      | DC - 3.0 GHz  |      | 25   |      | dB    |
|                                                                                                                  | 3.0 - 4.0 GHz |      | 20   |      | dB    |
|                                                                                                                  | 4.0 - 6.0 GHz |      | 12   |      | dB    |
| Input Power for 0.1 dB Compression<br>( $V_{ctl} = 3\text{V}$ )<br>( $V_{ctl} = 5\text{V}$ )                     | 0.5 - 6.0 GHz | 27   | 29   |      | dBm   |
|                                                                                                                  | 0.5 - 6.0 GHz | 32   | 34   |      | dBm   |
| Input Third Order Intercept<br>(Two-Tone Input Power = +7 dBm Each Tone)<br>( $V_{ctl} = 3\text{V}, 5\text{V}$ ) | 0.5 - 1.0 GHz |      | 56   |      | dBm   |
|                                                                                                                  | 1.0 - 3.0 GHz |      | 52   |      | dBm   |
|                                                                                                                  | 3.0 - 6.0 GHz |      | 48   |      | dBm   |
| Switching Speed<br>tRISE, tFALL (10/90% RF)<br>tON, tOFF (50% CTL to 10/90% RF)                                  | DC - 6.0 GHz  |      | 15   |      | ns    |
|                                                                                                                  |               |      | 30   |      | ns    |

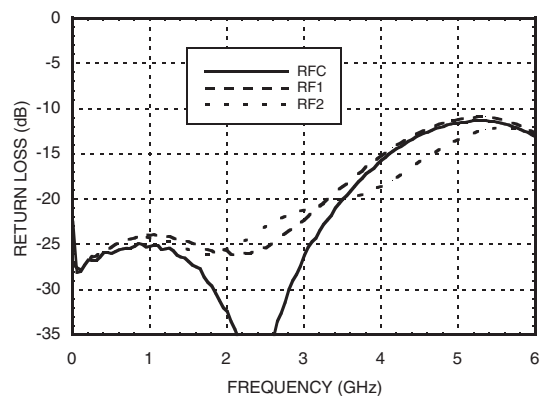
# HMC536MS8G / 536MS8GE

## GaAs MMIC POSITIVE CONTROL T/R SWITCH, DC - 6 GHz

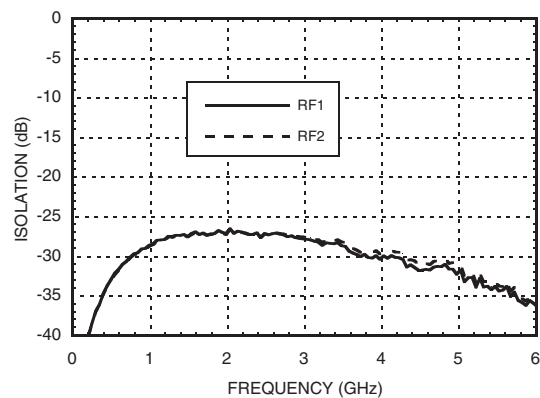
**Insertion Loss**



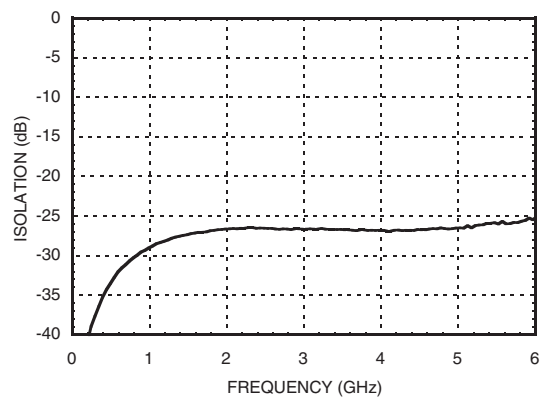
**Return Loss**



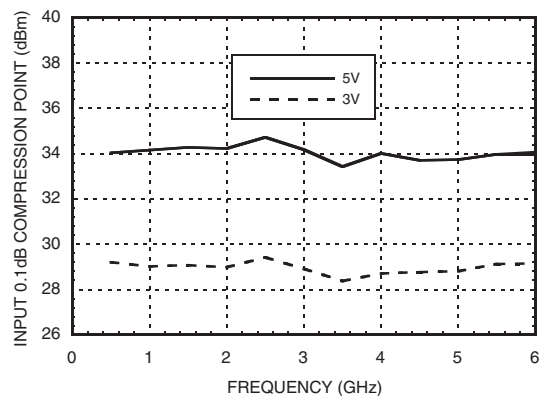
**Isolation Between  
Ports RFC and RF1 / RF2**



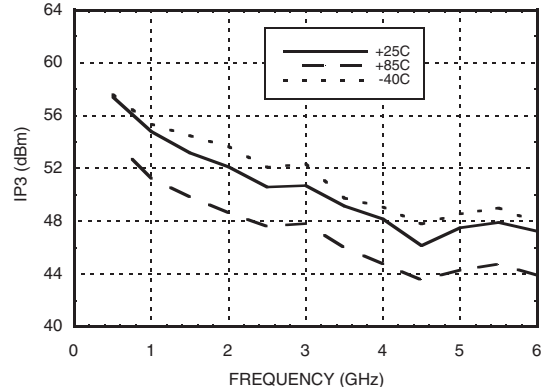
**Isolation Between Ports RF1 and RF2**



**Input 0.1 dB Compression Point**



**Input Third Order  
Intercept Point,  $V_{ctl} = 3V$**



# HMC536MS8G / 536MS8GE

## GaAs MMIC POSITIVE CONTROL T/R SWITCH, DC - 6 GHz

### Absolute Maximum Ratings

|                                                               |                  |
|---------------------------------------------------------------|------------------|
| Control Voltage Range                                         | -0.5 to +7.5 Vdc |
| Hot Switch Power Level<br>(Vctl = +3V)                        | +29 dBm          |
| Channel Temperature                                           | 150 °C           |
| Continuous Pdiss (T = 85 °C)<br>(derate 13 mW/°C above 85 °C) | 0.867 W          |
| Thermal Resistance                                            | 75 °C/W          |
| Storage Temperature                                           | -65 to +150 °C   |
| Operating Temperature                                         | -40 to +85 °C    |
| ESD Sensitivity (HBM)                                         | Class 1A         |

### Control Voltages

\*Control Input Tolerances are  $\pm 0.2$  Vdc

| State | Bias Condition*                       |
|-------|---------------------------------------|
| Low   | 0 Vdc @ 25 $\mu$ A Typical            |
| High  | +3 Vdc to +5 Vdc @ 25 $\mu$ A Typical |

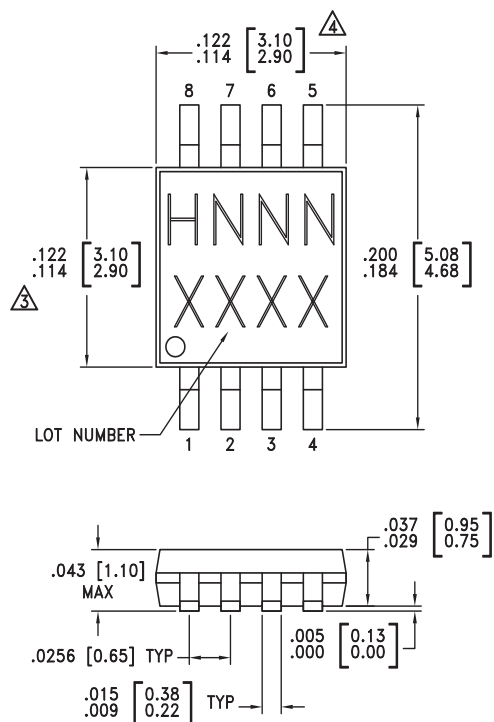
### Truth Table

| Control Input |      | Signal Path State |
|---------------|------|-------------------|
| A             | B    | RFC to:           |
| Low           | High | RF1               |
| High          | Low  | RF2               |

DC blocks are required at ports RFC, RF1, RF2.

Choose value for lowest frequency of operation.

### Outline Drawing



#### NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
4. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
5. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

### Package Information

| Part Number | Package Body Material                              | Lead Finish   | MSL Rating          | Package Marking <sup>[3]</sup> |
|-------------|----------------------------------------------------|---------------|---------------------|--------------------------------|
| HMC536MS8G  | Low Stress Injection Molded Plastic                | Sn/Pb Solder  | MSL1 <sup>[1]</sup> | H536<br>XXXX                   |
| HMC536MS8GE | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 <sup>[2]</sup> | H536<br>XXXX                   |

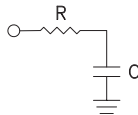
[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

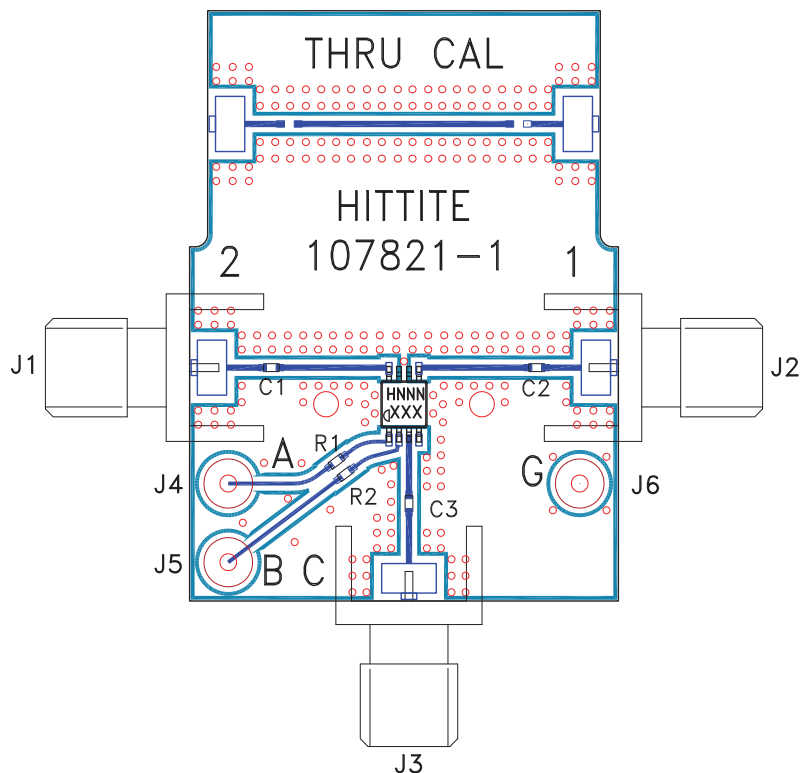
[3] 4-Digit lot number XXXX

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:  
20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373  
Order On-line at [www.hittite.com](http://www.hittite.com)

### Pin Descriptions

| Pin Number | Function      | Description                                                                                     | Interface Schematic                                                                 |
|------------|---------------|-------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|
| 1          | A             | See truth and control voltage tables.                                                           |  |
| 2          | B             | See truth and control voltage tables.                                                           |                                                                                     |
| 3, 5, 8    | RFC, RF1, RF2 | These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required.             |                                                                                     |
| 4          | N/C           | No connection required. This pin may be connected to RF/DC ground without affecting performance |                                                                                     |
| 6, 7       | GND           | Package bottom has exposed metal paddle that must also be connected to RF/DC ground.            |  |

## Evaluation PCB



## List of Materials for Evaluation PCB 105143 <sup>[1]</sup>

| Item    | Description                             |
|---------|-----------------------------------------|
| J1 - J3 | PCB Mount SMA RF Connector              |
| J4 - J6 | DC Pin                                  |
| C1 - C3 | 100 pF Capacitor, 0402 Pkg.             |
| R1 - R2 | 100 Ohm Resistor, 0402 Pkg.             |
| U1      | HMC536MS8G / HMC536MS8GE<br>SPDT Switch |
| PCB [2] | 107821 Evaluation PCB                   |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.



v03.0806



## HMC536MS8G / 536MS8GE

**GaAs MMIC POSITIVE CONTROL  
T/R SWITCH, DC - 6 GHz**

**Notes:**

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SWITCHES - SMT